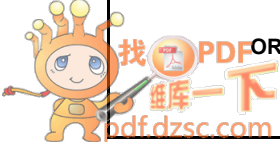


 <p><b>POSEICO</b> POSEICO SPA Power SEMiconductors Italian COporation</p>	<p>POSEICO SPA Via N. Lorenzi 8, 16152 Genova - ITALY Tel. ++ 39 010 6556234 - Fax ++ 39 010 6557519 Sales Office: Tel. ++ 39 010 6556775 - Fax ++ 39 010 6442510</p>
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<b>FAST RECOVERY DIODE</b>	<h1>ARF370</h1>	
	Repetitive voltage up to	<b>4500 V</b>
	Mean forward current	<b>485 A</b>
	Surge current	<b>4 kA</b>
<b>FINAL SPECIFICATION</b>		
feb 97 - ISSUE : 04		

Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
<b>BLOCKING</b>					
V <sub>RRM</sub>	Repetitive peak reverse voltage		150	4500	V
V <sub>RSM</sub>	Non-repetitive peak reverse voltage		150	4600	V
I <sub>RRM</sub>	Repetitive peak reverse current	V=VRRM	150	50	mA
<b>CONDUCTING</b>					
I <sub>F(AV)</sub>	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		485	A
I <sub>F(AV)</sub>	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		490	A
I <sub>FSM</sub>	Surge forward current	Sine wave, 10 ms	150	4	kA
I <sup>2</sup> t	I <sup>2</sup> t	reapplied reverse voltage up to 50% VRSM		80 x1E3	A²s
V <sub>FM</sub>	Forward voltage	Forward current = 1200 A	25	3.4	V
V <sub>F(TO)</sub>	Threshold voltage		150	1.74	V
r <sub>F</sub>	Forward slope resistance		150	1.700	mohm
<b>SWITCHING</b>					
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 1000 A di/dt= 100 A/μs VR = 100 V	150	5	μs
Q <sub>rr</sub>	Reverse recovery charge			700	μC
I <sub>rr</sub>	Peak reverse recovery current			280	A
s	Softness (s-factor), min			0.5	
V <sub>FR</sub>	Peak forward recovery	di/dt= 400 A/μs	150	80	V
<b>MOUNTING</b>					
R <sub>th(j-h)</sub>	Thermal impedance	Junction to heatsink, double side cooled		52	°C/kW
T <sub>j</sub>	Operating junction temperature			-30 / 150	°C
F	Mounting force			8.4 / 9.4	kN
	Mass			280	g



ORDERING INFORMATION : ARF370 S 45

standard specification   VRRM/100

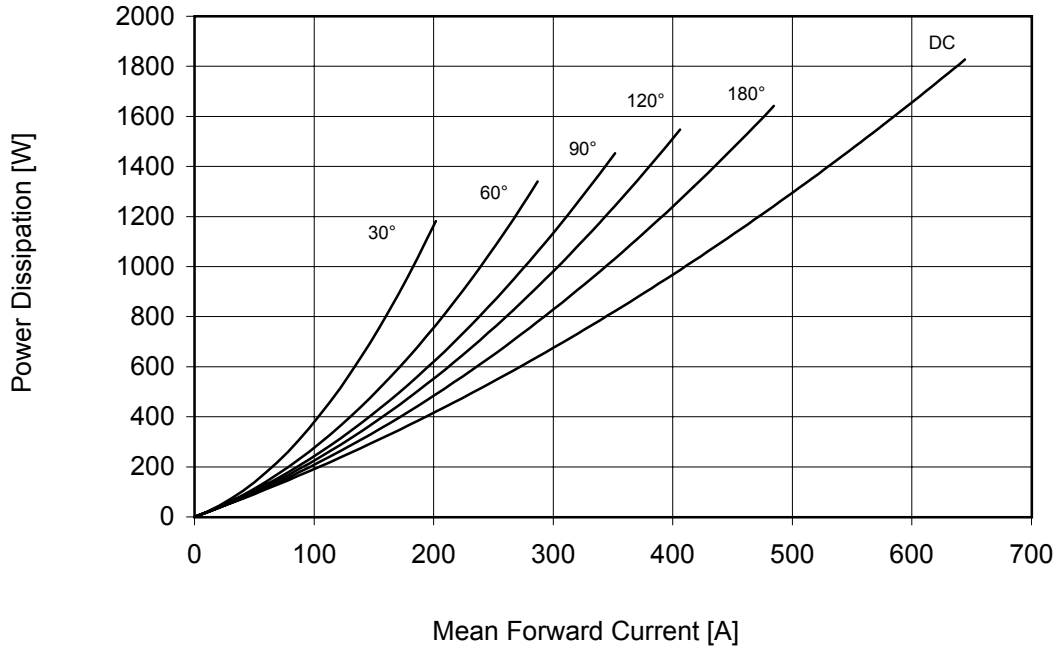
# ARF370 FAST RECOVERY DIODE



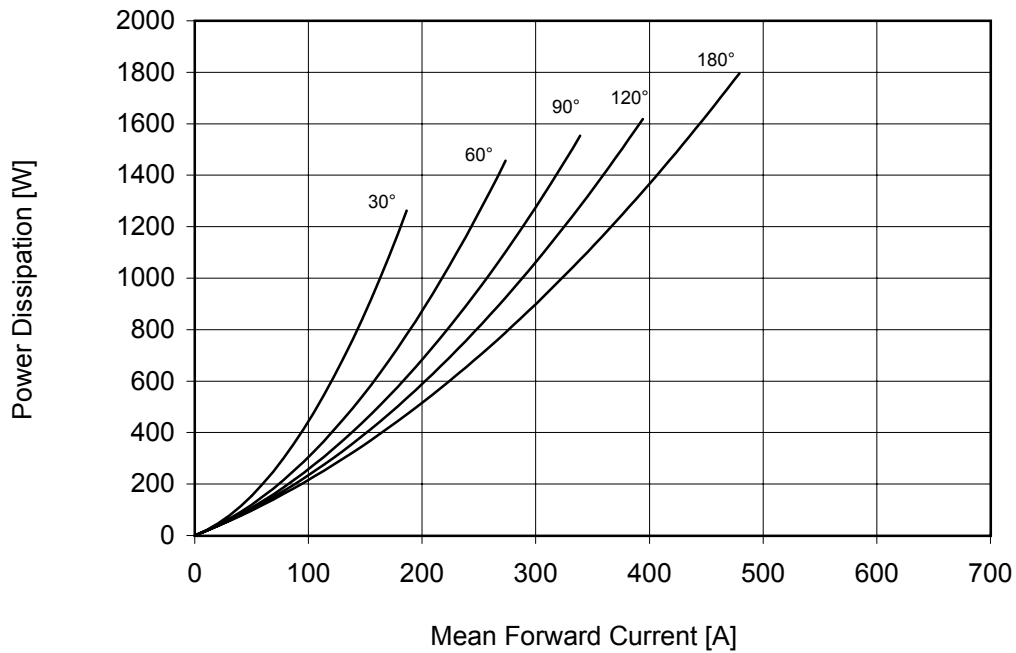
FINAL SPECIFICATION feb 97 - ISSUE : 04

## DISSIPATION CHARACTERISTICS

### SQUARE WAVE



### SINE WAVE



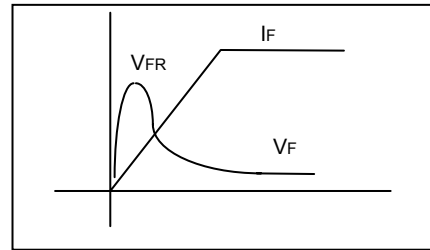
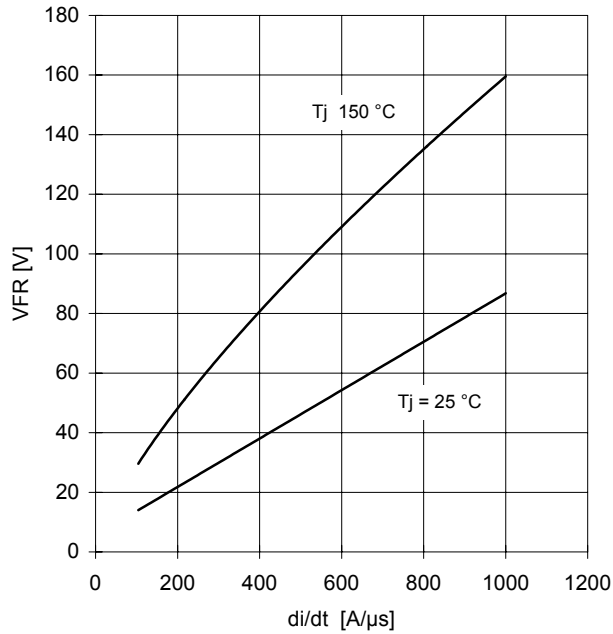
# ARF370 FAST RECOVERY DIODE



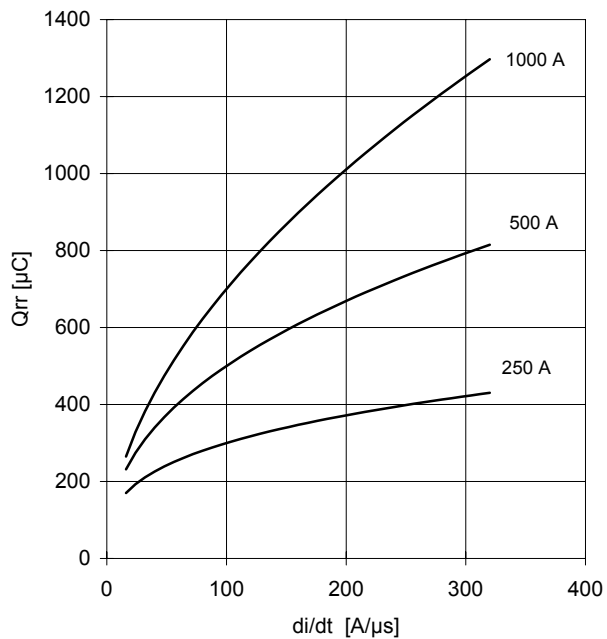
FINAL SPECIFICATION feb 97 - ISSUE : 04

## SWITCHING CHARACTERISTICS

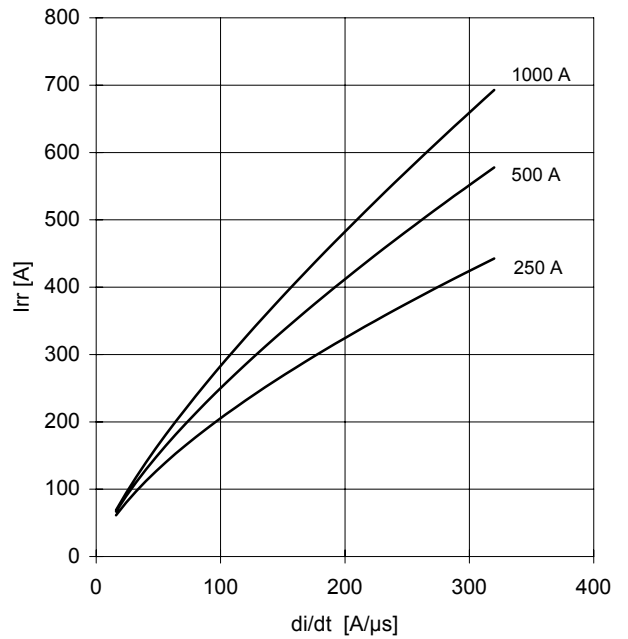
FORWARD RECOVERY VOLTAGE



REVERSE RECOVERY CHARGE - Tj = 150°



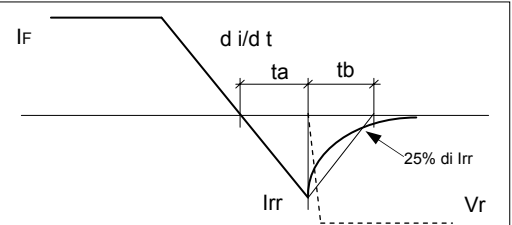
REVERSE RECOVERY CURRENT - Tj = 150°



$$t_a = I_{rr} / (di/dt) \quad t_b = t_{rr} - t_a$$

$$\text{Softness (s factor)} \quad s = t_b / t_a$$

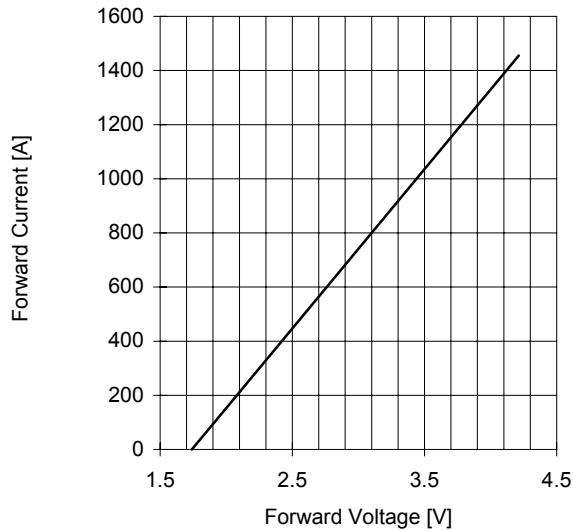
$$\text{Energy dissipation during recovery} \quad E_r = V_r \cdot (Q_{rr} - I_{rr} \cdot t_a / 2)$$



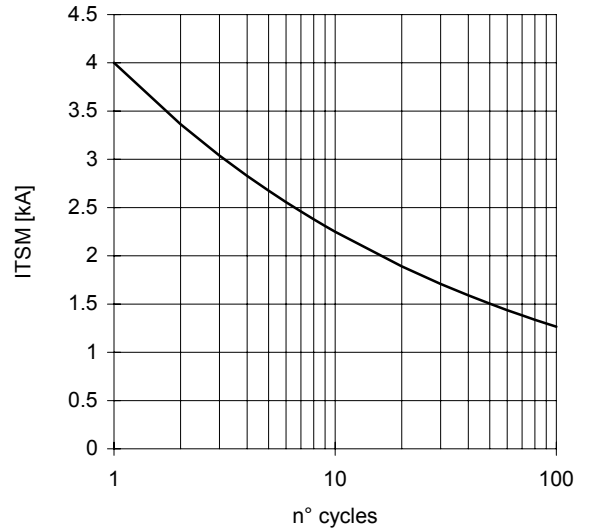
# ARF370 FAST RECOVERY DIODE

FINAL SPECIFICATION feb 97 - ISSUE : 04

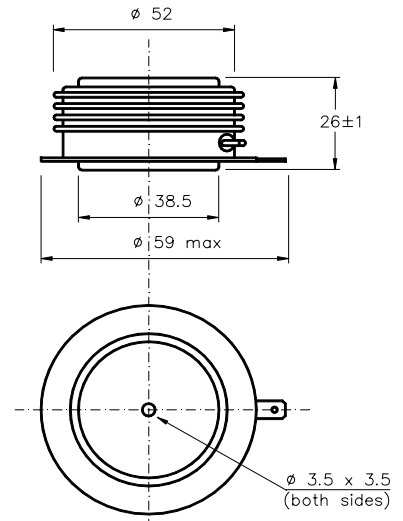
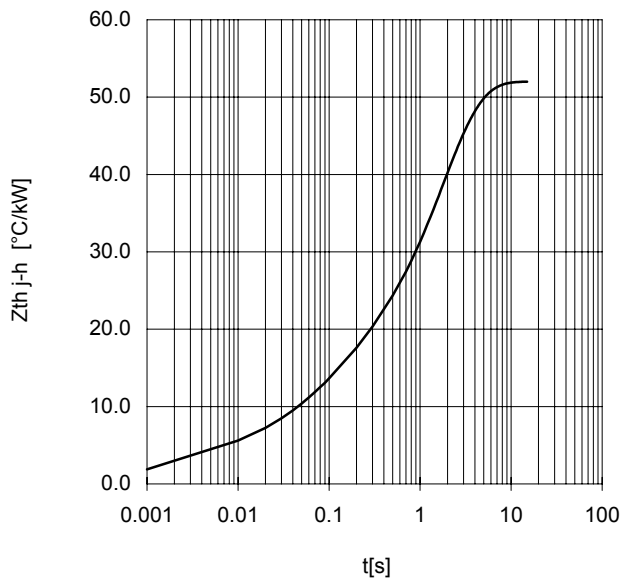
FORWARD CHARACTERISTIC  
 $T_j = 150^\circ\text{C}$



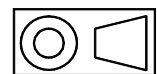
SURGE CHARACTERISTIC  
 $T_j = 150^\circ\text{C}$



TRANSIENT THERMAL IMPEDANCE  
DOUBLE SIDE COOLED



Dimensions  
in mm



All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2  $\mu\text{m}$ .

In the interest of product improvement POSEICO SPA reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

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